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# For Muting (20V, 0.3A)

## 2SD2704K

### ●Features

- 1) High DC current gain.  
 $h_{FE} = 820$  to  $2700$
- 2) High emitter-base voltage.  
 $V_{EBO} = 25V$  (Min.)
- 3) Low  $R_{on}$   
 $R_{on} = 0.7\Omega$  (Typ.)

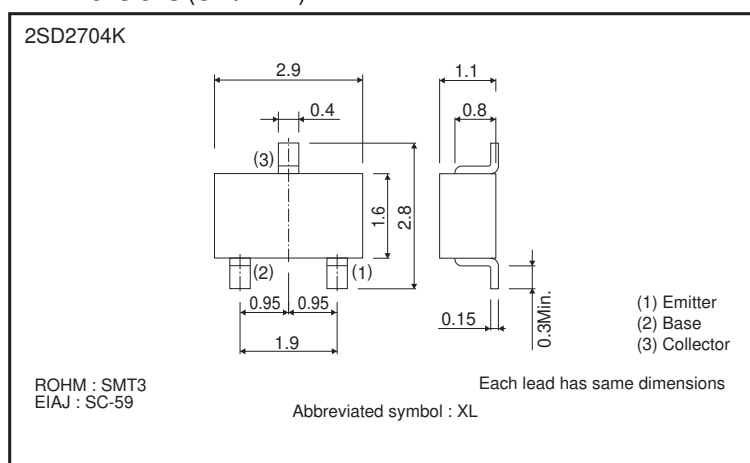
### ●Structure

Epitaxial planar type  
NPN silicon transistor

### ●Packaging specifications

Type	Package	Taping
	Code	T146
	Basic ordering unit (pieces)	3000
2SD2704K		○

### ●Dimensions (Unit : mm)



### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	$V_{CEO}$	20	V
Emitter-base voltage	$V_{EBO}$	25	V
Collector current	$I_C$	0.3	A
Collector power dissipation	$P_C$	0.2	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	50	—	—	V	$I_C = 10\mu A$
Collector-emitter breakdown voltage	$BV_{CEO}$	20	—	—	V	$I_C = 1mA$
Emitter-base breakdown voltage	$BV_{EBO}$	25	—	—	V	$I_E = 10\mu A$
Collector cutoff current	$I_{CBO}$	—	—	0.1	$\mu A$	$V_{CB} = 50V$
Emitter cutoff current	$I_{EBO}$	—	—	0.1	$\mu A$	$V_{EB} = 25V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	50	100	mV	$I_C/I_B = 30mA/3mA$
DC current transfer ratio	$h_{FE}$	820	—	2700	—	$V_{CE} = 2V, I_C = 4mA$
Transition frequency	$f_T$ *	—	35	—	MHz	$V_{CE} = 6V, I_E = -4mA, f = 10MHz$
Output capacitance	$C_{ob}$	—	3.9	—	pF	$V_{CB} = 10V, I_E = 0A, f = 1MHz$
Output On-resistance	$R_{on}$	—	0.7	—	$\Omega$	$I_B = 5mA, V_i = 100mV(rms), f = 1kHz$

\* Measured using pulse current

# **Electrical characteristic curves**

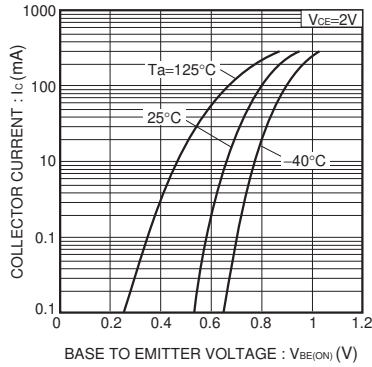


Fig.1 Grounded emitter propagation characteristics (I)

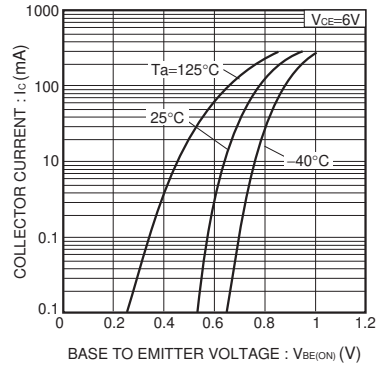


Fig.2 Grounded emitter propagation characteristics (II)

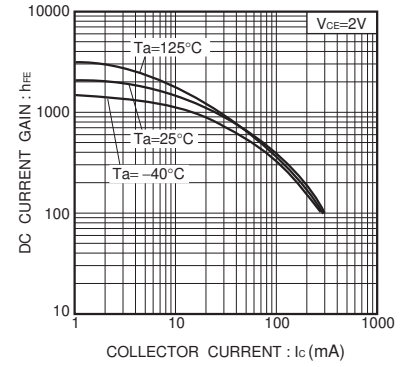


Fig.3 DC current gain vs. collector current (I)

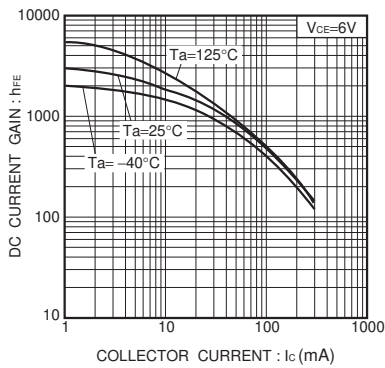


Fig.4 DC current gain vs. collector current (II)

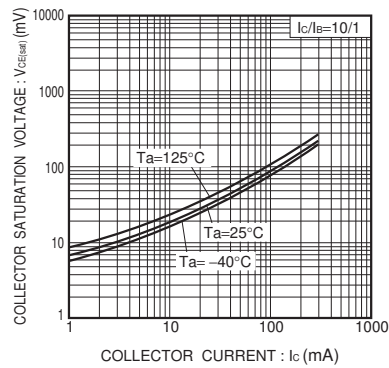


Fig.5 Collector-emitter saturation voltage vs. collector current (I)

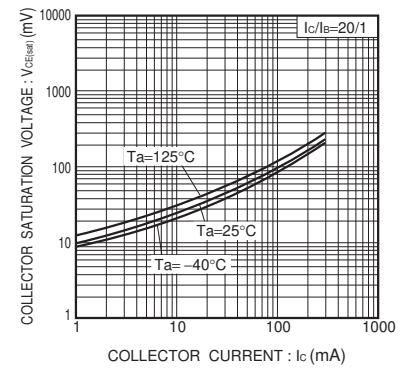


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

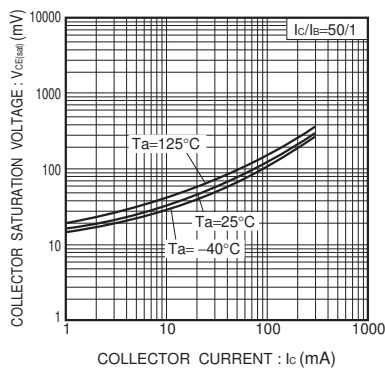


Fig.7 Collector-emitter saturation voltage vs. collector current (III)

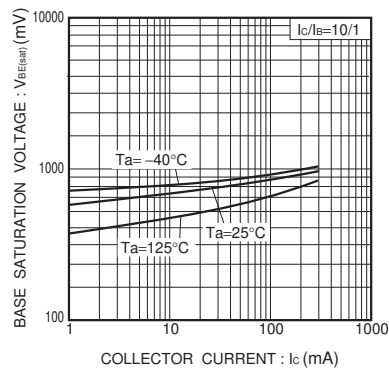


Fig.8 Base-emitter saturation voltage vs. collector current (I)

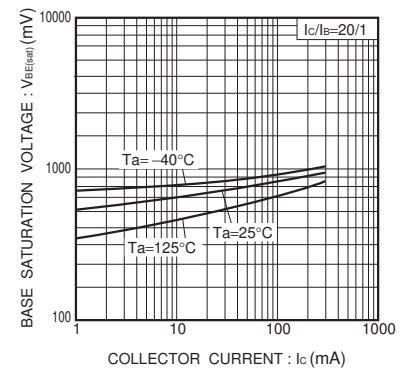


Fig.9 Base-emitter saturation voltage vs. collector current (II)

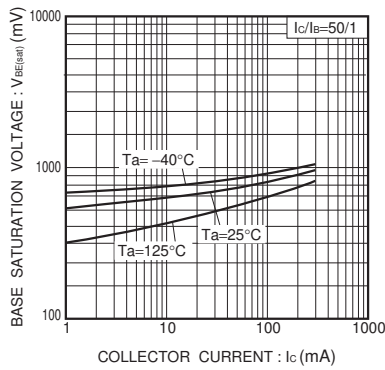


Fig.10 Base-emitter saturation voltage vs. collector current (III)

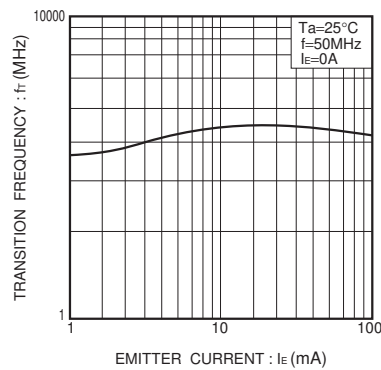


Fig.11 Gain bandwidth product vs. emitter current

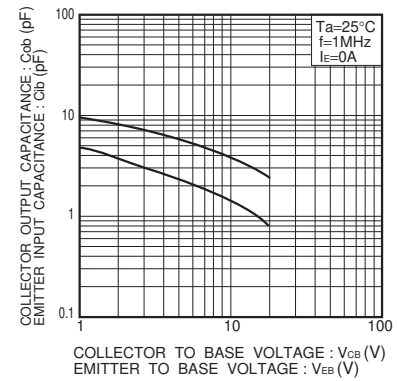
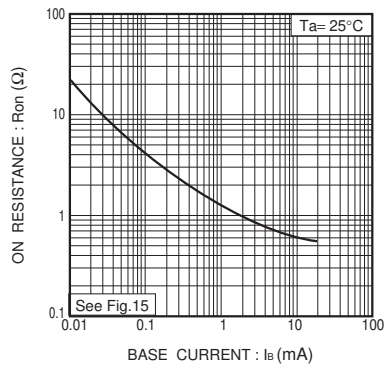
Fig.12 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

Fig.13 Output-on resistance vs. base current (I)

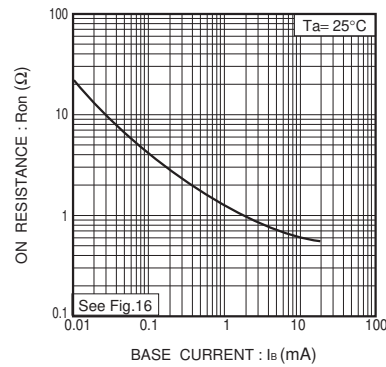


Fig.14 Output-on resistance vs. base current (II)

### ● Ron measurement circuit

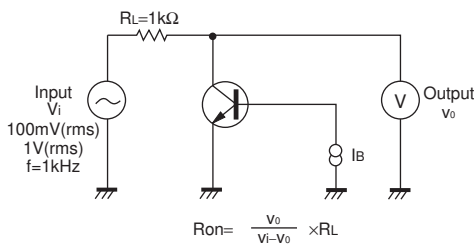


Fig.15 Ron measurement circuit (I)

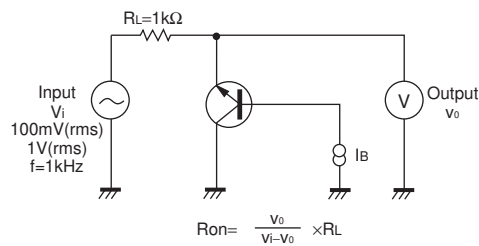


Fig.16 Ron measurement circuit (II)

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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